## NSN 5961-00-004-0149

Transistor - Page 1 of 2



View Online at https://aerobasegroup.com/psn/5961-00-004-0140

View Online at https://aerobasegroup.com/nsn/5961-00-004-0149
nclosure Material:
Metal
Overall Length:
1.218 inches
Overall Diameter:
0.380 inches
Mounting Facility Quantity:
1
nternal Configuration:
Junction contact
Joint Electronic Device Engineering Council/jedec/case Outline Designation:
Го-111
Mounting Method:
Threaded stud
Features Provided:
Hermetically sealed case
Overall Width Across Flats:
0.437 inches
Thread Size:
0.190 inches
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
100.0 collector to base voltage/static/emitter open and 80.0 collector to emitter voltage/static/base open and 6.0 emitter to base voltage,
static, collector open
Current Rating Per Characteristic:
5.00 amperes source cutoff current
Power Rating Per Characteristic:
37.0 watts small-signal input power, common-collector absolute
Maximum Operating Tempurature Per Measurement Point:
200.0 degrees celsius ambient air
Special Features:
Junction pattern arrangement: npn
Test Data Document:
32577-928436 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.;
excludes any specification, standard or other document that may be referenced in a basic governing drawing)
Thread Series Designator:
Jnf
Terminal Type And Quantity:
3 tab, solder lug and 1 wire hook
Shelf Life:
N/a

**Unit Of Measure:** 

## **NSN 5961-00-004-0149** Transistor - Page 2 of 2



em			

No

Fiig:

A110a0